

LL4148 Fast Switching Diodes
Feature

- V_R 75V
- I_{FAV} 150mA

Application

- Extreme fast switches


ABSOLUTE MAXIMUM RATINGS ($T_a=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Non-Repetitive Peak Reverse Voltage	V_{RSM}	100	V
Repetitive Peak Reverse Voltage	V_{RRM}	75	V
Average rectified output current	I_o	0.15	A
Forward continuous current	I_{FM}	0.30	A
Non-repetitive Peak Forward Surge Current @ $t=1\ \mu\text{s}$	I_{FSM}	2	A
Non-repetitive Peak Forward Surge Current @ $t=1\ \text{s}$		1	A
Power Dissipation	P_D	0.4	W
Junction Temperature	T_J	125	$^\circ\text{C}$
Storage Temperature	T_{STG}	-65 ~ +150	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Max	Unit
Forward voltage	V_F	$I_F=50\text{mA}$		1.0	V
Reverse current	I_R	$V_R=20\text{V}$		25	nA
		$V_R=75\text{V}$		5	μA
Diode capacitance	C_D	$V_R=0\text{V}, f=1\text{MHz}$		4	pF
Reverse Recovery Time	t_{rr}	$I_F=I_R=10\text{mA}, I_{tr}=0.1*I_R,$ $R_L=100\Omega, V_R=6\text{V}$		4	ns

Typical Electrical and Thermal Characteristics

FIG1: Forward Current vs. Forward Voltage

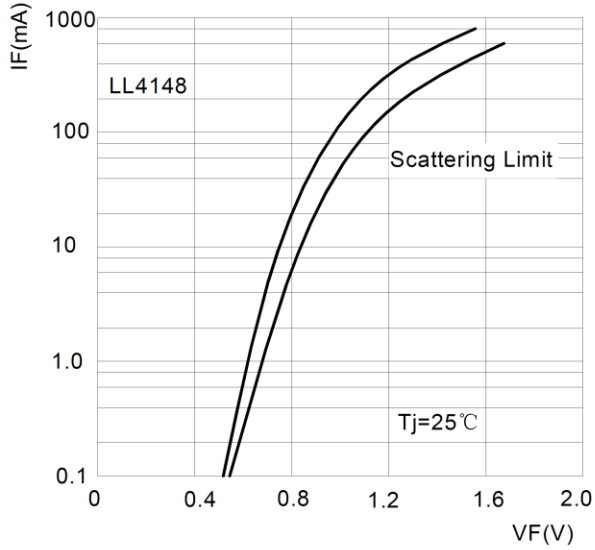


FIG2: Reverse Current vs. Reverse Voltage

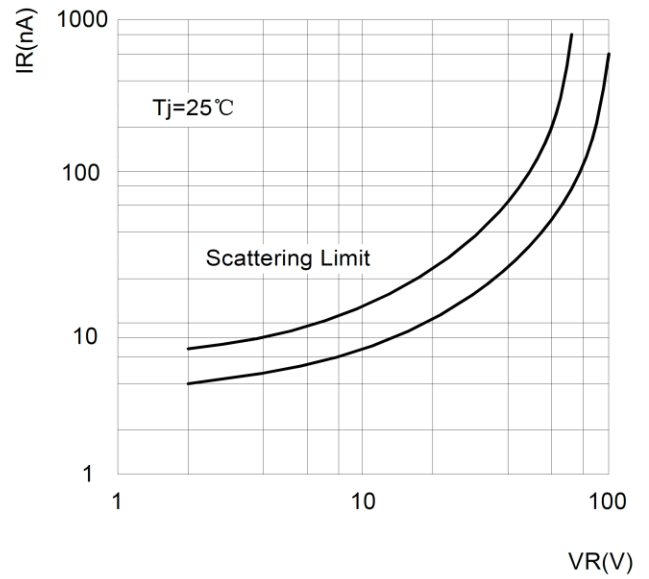
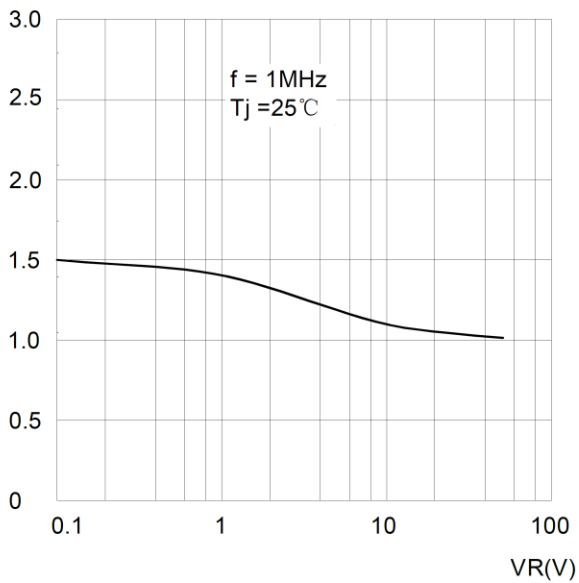
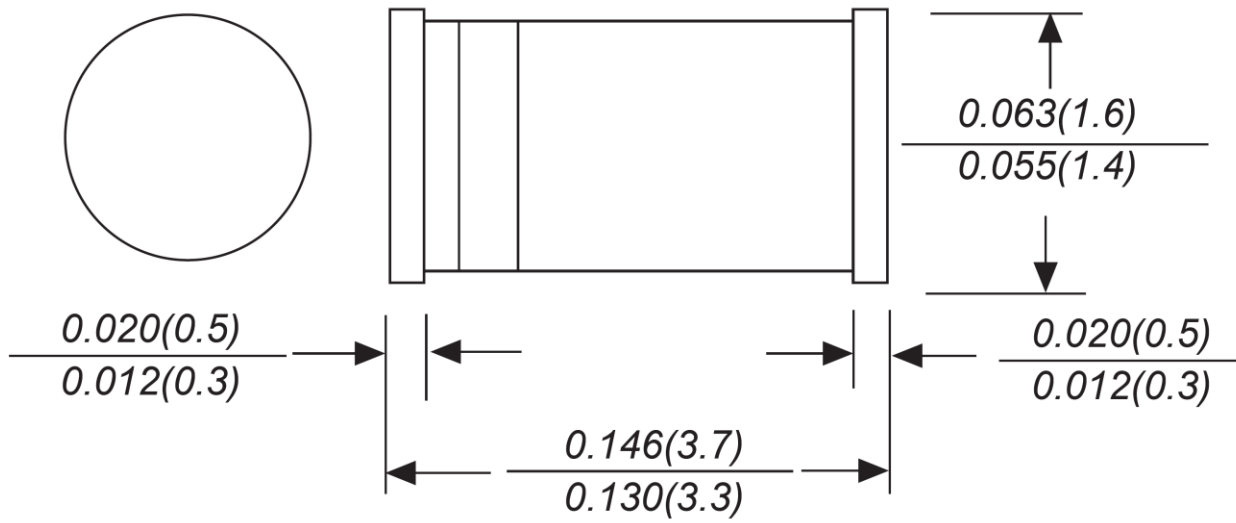


FIG3: Diode Capacitance vs. Reverse Voltage

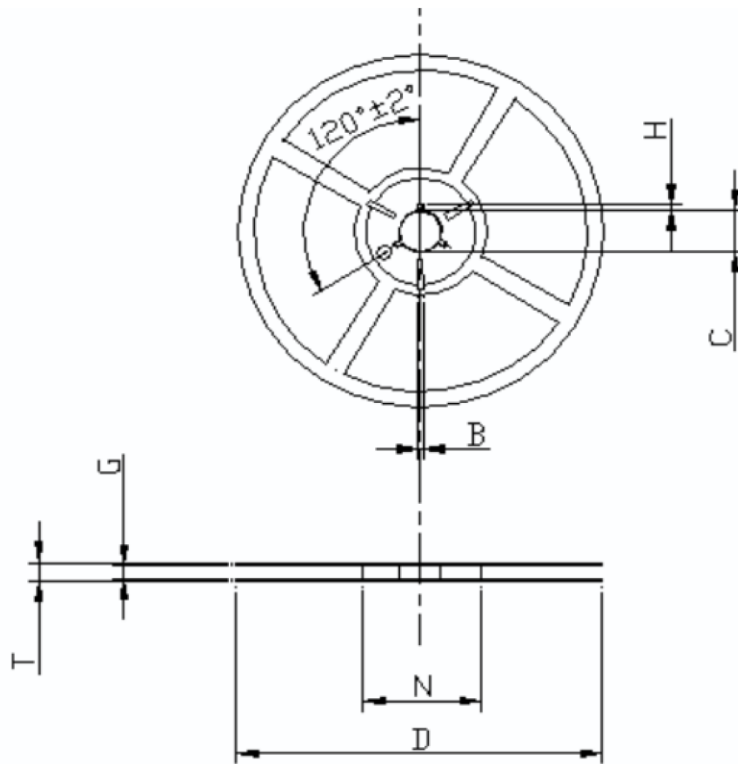


MINI MELF Package Outline Dimensions

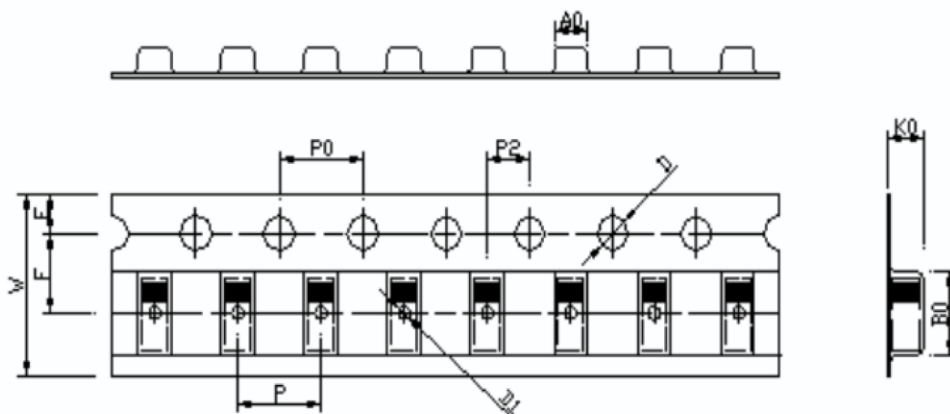


Dimensions in millimeters

Reel Taping Specifications For MINI MELF



SYMBOL	B	C	D	G	H	N	T
SIZE(mm)	2±0.5	13±0.5	178±2	8.4±1.5	4±0.5	60	<14.9



SYMBOL	W	P	E	F	D	D1	P0	P2	A0	B0	K0
SIZE(mm)	8.0±0.1	4.0±0.1	1.75±0.1	3.5±0.05	1.5±0.1	1.0±0.1	4.0±0.1	2.0±0.05	1.70±0.1	3.80±0.1	1.85±0.1